Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:
Glass
Overall Length:
0.200 inches
Terminal Length:
1.500 inches
Overall Diameter:
0.090 inches
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
Do-35
Mounting Method:
Terminal
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
48.0 nonrepetitive peak reverse voltage and 40.0 working peak reverse voltage and 40.0 reverse voltage, instantaneous
Current Rating Per Characteristic:
5.00 amperes forward current, average preset
Capacitance Rating In Picofarads:
70.0
Maximum Operating Tempurature Per Measurement Point:
150.0 degrees celsius junction
Terminal Type And Quantity:
2 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
-
Demilitarization:
Yes - demil/mli
Fiig:
A110a0